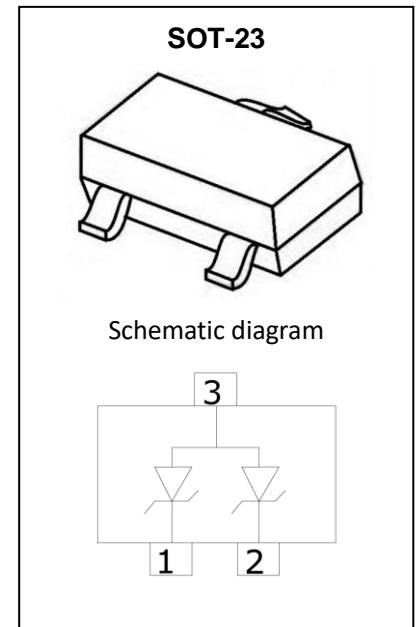


Product Summary

The GESDQ5V0C2 is an uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The dual-junction common-anode design allows the user to protect one bidirectional data line or two

Feature

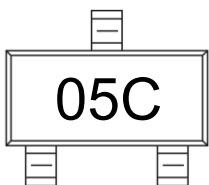
- Small package for use in portable electronics
- Low reverse clamping voltage
- Low leakage current
- Fast response time <1ns
- Meets MSL 1 Requirements
- IEC 61000-4-2 Level 4 ESD protection



Application

- Data lines
- Industrial Controls
- Cellular handsets AND accessories
- Portable instrumentation
- Peripherals
- Notebook Computers
- Set-Top Box
- Projection TV

Marking



Absolute Maximum Ratings ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter		Symbol	Value	Unit
IEC 61000-4-2 ESD Voltage	Air Model	$V_{ESD}^{1)}$	± 15	kV
IEC 61000-4-2 ESD Voltage	Contact Model		± 8	
JESD22-A114-B ESD Voltage	Per Human Body Model		± 8	
ESD Voltage	Machine Model		± 0.4	
Peak Pulse Power		$P_{PP}^{2)}$	300	W
Peak Pulse Current		$I_{PP}^{2)}$	17	A
Lead Solder Temperature – Maximum (10 Second Duration)		T_L	260	$^\circ\text{C}$
Junction Temperature		T_j	150	$^\circ\text{C}$
Storage Temperature		T_{stg}	-55~+150	$^\circ\text{C}$

1) Device stressed with ten non-repetitive ESD pulses.

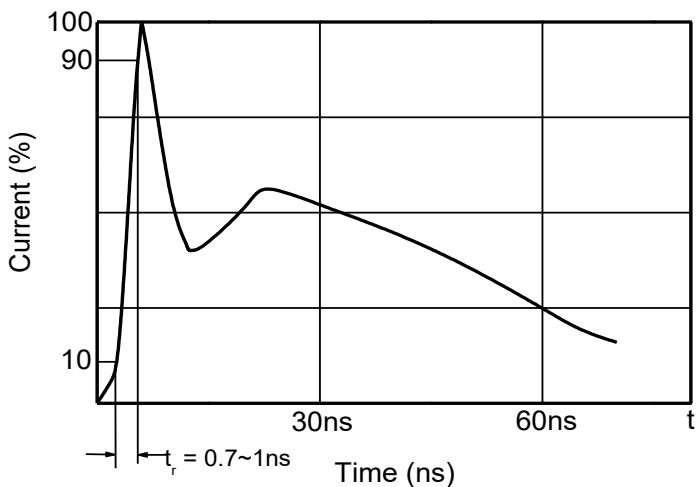
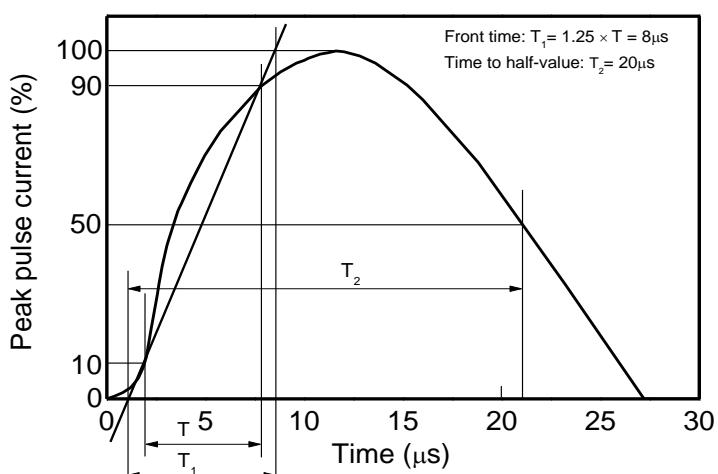
2) Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC61000-4-5.

ESD standards compliance
IEC61000-4-2 Standard

Contact Discharge		Air Discharge	
Level	Test Voltage kV	Level	Test Voltage kV
1	2	1	2
2	4	2	4
3	6	3	8
4	8	4	15

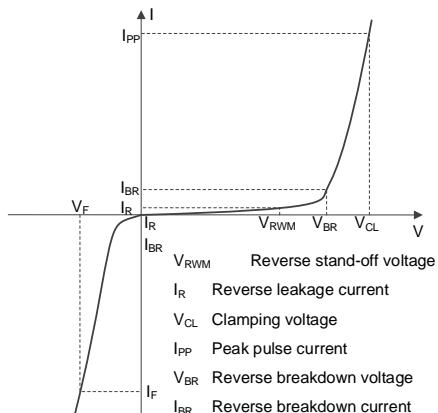
JESD22-A114-B Standard

ESD Class	Human Body Discharge V
0	0~249
1A	250~499
1B	500~999
1C	1000~1999
2	2000~3999
3A	4000~7999
3B	8000~15999

Contact discharge current waveform per IEC61000-4-2

8/20 μs waveform per IEC61000-4-5


Electrical Parameter

Symbol	Parameter
V_C	Clamping Voltage @ I_{PP}
I_{PP}	Peak Pulse Current
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_R	Reverse Leakage Current @ V_{RWM}
V_{RWM}	Reverse Standoff Voltage



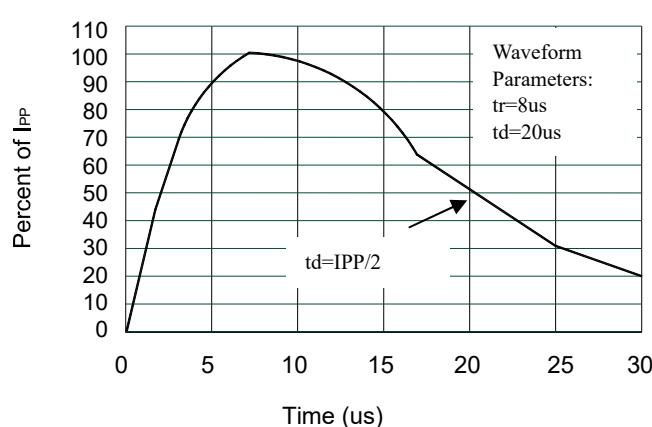
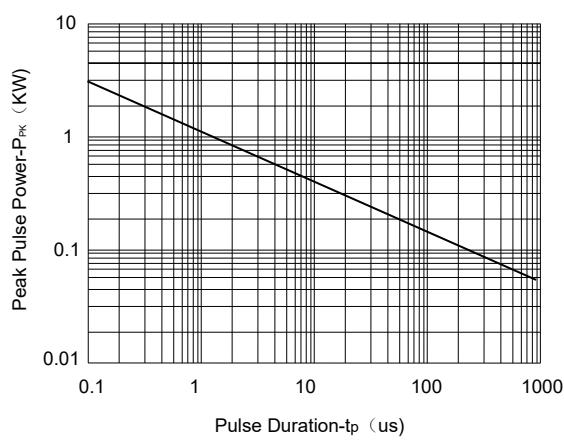
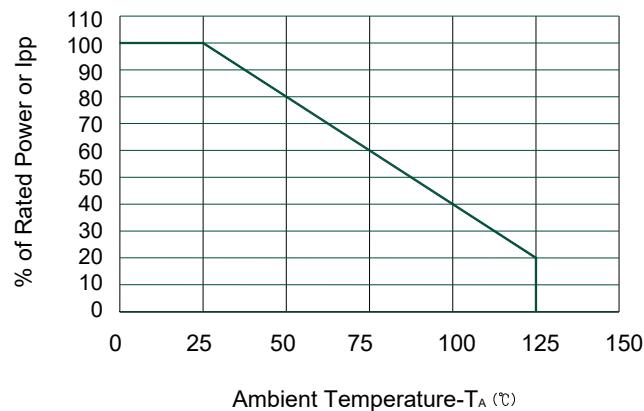
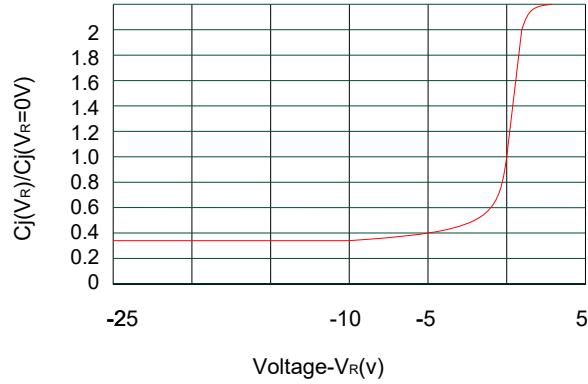
V-I characteristics for a Uni-directional TVS

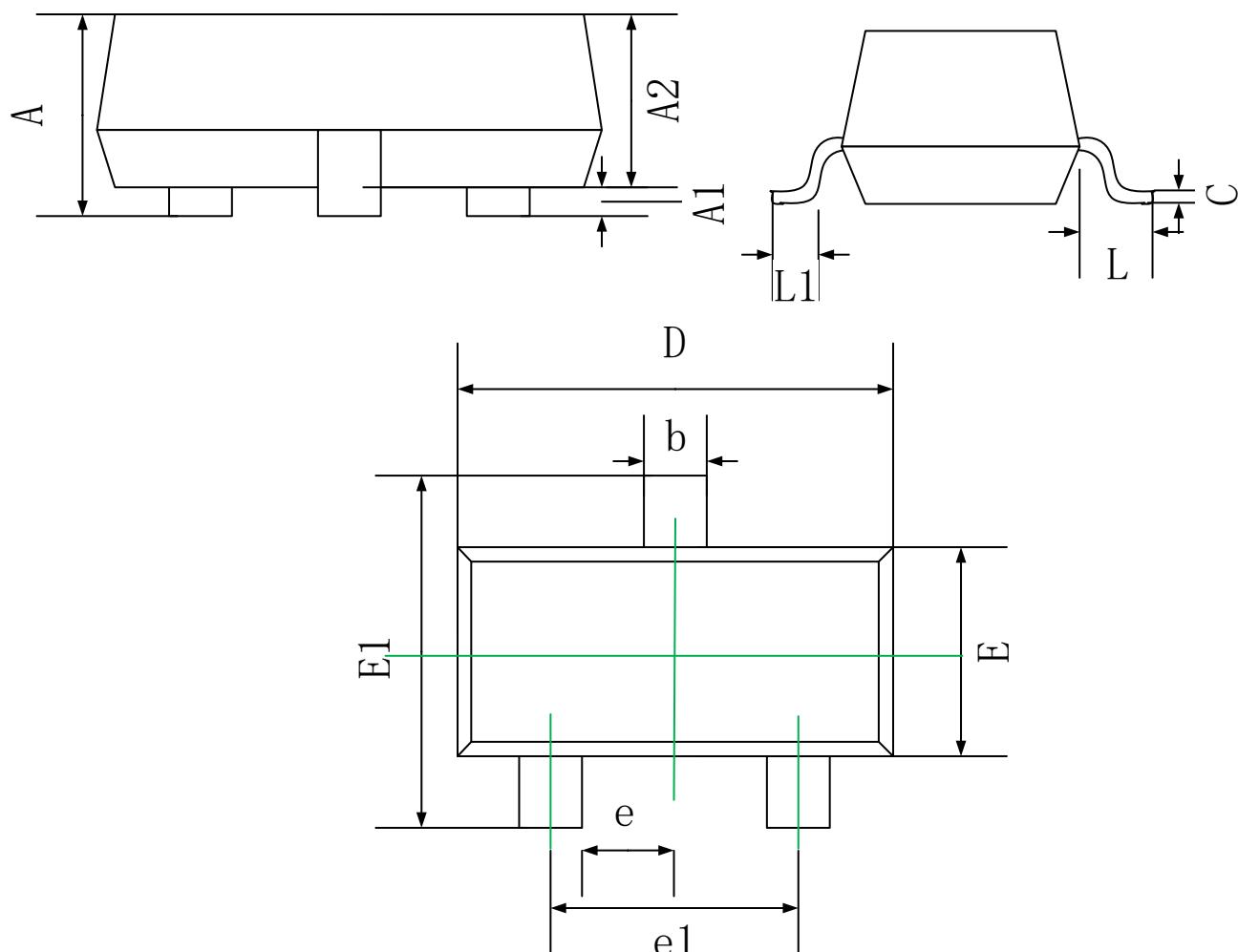
Electrical Characteristics ($T_a=25^\circ C$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse stand-off voltage	$V_{RWM}^1)$				5	V
Reverse leakage current	I_R	$V_{RWM}=5V$			1	uA
Breakdown voltage	V_{BR}	$I_T=1mA$	6			V
Clamping voltage	$V_C^2)$	$I_{PP}=1A$		9.8		V
		$I_{PP}=17A$			17	V
Junction capacitance	C_J	$V_R=0V, f=1MHz$		150	250	pF

1) Other voltages available upon request.

2) Non-repetitive current pulse 8/20μs exponential decay waveform according to IEC61000-4-5

Typical Characteristics

Pulse Waveform

Non-Repetitive Peak Pulse Power vs. Pulse Time

Ambient Temperature- T_A (°C)
Power Derating Curve

Junction Capacitance vs. Reverse Voltage

SOT-23 Package Outline Dimensions


Symbol	Dimensions In Millimeters	
	Min.	Max.
A	0.90	1.15
A1	0.00	0.10
A2	0.90	1.05
b	0.30	0.50
c	0.08	0.15
D	2.80	3.00
E	1.20	1.40
E1	2.25	2.55
e	0.95 REF.	
e1	1.80	2.00
L	0.55 REF.	
L1	0.30	0.50